

DATA SHEET



MPS3904 NPN switching transistor

Product specification
Supersedes data of 1997 Mar 03

1999 Apr 12

NPN switching transistor

MPS3904

FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 40 V).

APPLICATIONS

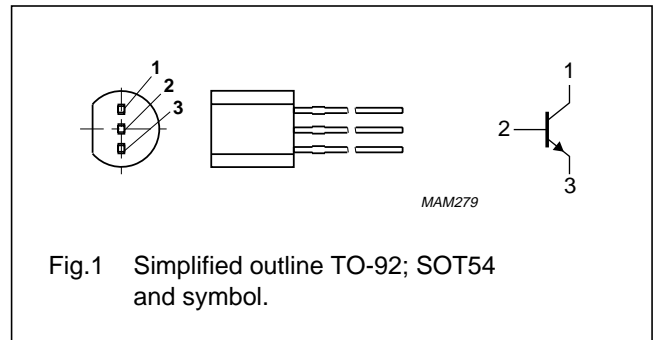
- General purpose switching and amplification.

DESCRIPTION

NPN transistor in a TO-92; SOT54 plastic package.
PNP complement: MPS3906.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | collector |
| 2 | base |
| 3 | emitter |



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|-------------------------------|---|------|------|------------------|
| V_{CBO} | collector-base voltage | open emitter | – | 60 | V |
| V_{CEO} | collector-emitter voltage | open base | – | 40 | V |
| V_{EBO} | emitter-base voltage | open collector | – | 6 | V |
| I_C | collector current (DC) | | – | 100 | mA |
| I_{CM} | peak collector current | | – | 200 | mA |
| I_{BM} | peak base current | | – | 200 | mA |
| P_{tot} | total power dissipation | $T_{amb} \leq 25\text{ }^\circ\text{C}$ | – | 500 | mW |
| T_{stg} | storage temperature | | –65 | +150 | $^\circ\text{C}$ |
| T_j | junction temperature | | – | 150 | $^\circ\text{C}$ |
| T_{amb} | operating ambient temperature | | –65 | +150 | $^\circ\text{C}$ |

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MPS3904

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------|---|------------|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1 | 250 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-------------|--------------------------------------|---|-----------------------------|-------------------------|----------|
| I_{CBO} | collector cut-off current | $I_E = 0$; $V_{CB} = 30\text{ V}$ | – | 50 | nA |
| I_{EBO} | emitter cut-off current | $I_C = 0$; $V_{EB} = 5\text{ V}$ | – | 50 | nA |
| h_{FE} | DC current gain | $V_{CE} = 1\text{ V}$; note 1 $I_C = 0.1\text{ mA}$ $I_C = 1\text{ mA}$ $I_C = 10\text{ mA}$ $I_C = 50\text{ mA}$ $I_C = 100\text{ mA}$ | 40 70 100 60 30 | – – 300 – – | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 10\text{ mA}$; $I_B = 1\text{ mA}$; note 1 $I_C = 50\text{ mA}$; $I_B = 5\text{ mA}$; note 1 | – – | 200 300 | mV mV |
| V_{BEsat} | base-emitter saturation voltage | $I_C = 10\text{ mA}$; $I_B = 1\text{ mA}$; note 1 $I_C = 50\text{ mA}$; $I_B = 5\text{ mA}$; note 1 | 650 – | 850 950 | mV mV |
| C_c | collector capacitance | $I_E = i_e = 0$; $V_{CB} = 5\text{ V}$; $100\text{ kHz} \leq f \leq 1\text{ MHz}$ | – | 5 | pF |
| C_e | emitter capacitance | $I_C = i_c = 0$; $V_{EB} = 0.5\text{ V}$; $100\text{ kHz} \leq f \leq 1\text{ MHz}$ | – | 15 | pF |
| f_T | transition frequency | $I_C = 10\text{ mA}$; $V_{CE} = 20\text{ V}$; $f = 100\text{ MHz}$ | 180 | – | MHz |
| F | noise figure | $I_C = 100\text{ }\mu\text{A}$; $V_{CE} = 5\text{ V}$; $R_S = 1\text{ k}\Omega$; $f = 10\text{ Hz}$ to 15.7 kHz | – | 5 | dB |

Switching times (between 10% and 90% levels); (see Fig.2)

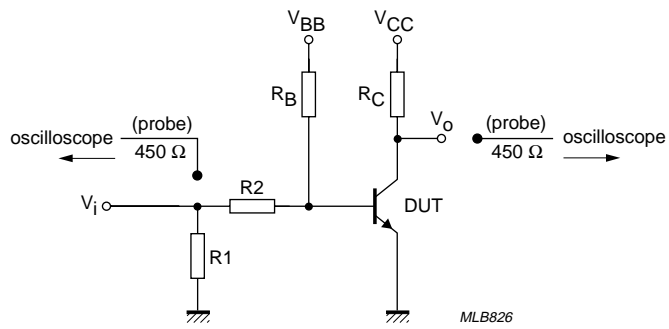
| | | | | | |
|-----------|---------------|--|---|------|----|
| t_{on} | turn-on time | $I_{Con} = 10\text{ mA}$; $I_{Bon} = 1\text{ mA}$; $I_{Boff} = -1\text{ mA}$; $V_{CC} = 3\text{ V}$; $V_{BB} = -1.9\text{ V}$ | – | 110 | ns |
| t_d | delay time | | – | 50 | ns |
| t_r | rise time | | – | 60 | ns |
| t_{off} | turn-off time | | – | 1200 | ns |
| t_s | storage time | | – | 1000 | ns |
| t_f | fall time | | – | 200 | ns |

Note

1. Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta = 0.02$.

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$V_i = 5\text{ V}$; $t_p \geq 4\text{ }\mu\text{s}$; $t_r = t_f \leq 3\text{ ns}$.
 $R_1 = 56\text{ }\Omega$; $R_2 = 2.5\text{ k}\Omega$; $R_B = 3.9\text{ k}\Omega$; $R_C = 270\text{ }\Omega$.
 Oscilloscope: input impedance $Z_i = 50\text{ }\Omega$.

Fig.2 Test circuit for switching times.

NPN switching transistor

MPS3904

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

| UNIT | A | b | b ₁ | c | D | d | E | e | e ₁ | L | L ₁ ⁽¹⁾ |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|-------------------------------|
| mm | 5.2 5.0 | 0.48 0.40 | 0.66 0.56 | 0.45 0.40 | 4.8 4.4 | 1.7 1.4 | 4.2 3.6 | 2.54 | 1.27 | 14.5 12.7 | 2.5 |

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|-----------------|------------|-------|-------|---------------------|------------|
| | IEC | JEDEC | EIAJ | | |
| SOT54 | | TO-92 | SC-43 | | 97-02-28 |

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MPS3904

DEFINITIONS

| Data Sheet Status | |
|---|---|
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |

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MPS3904

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